

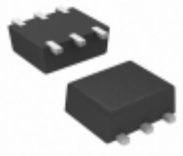

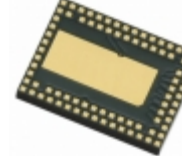
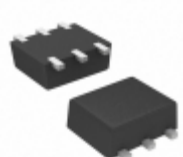

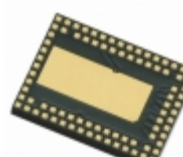

	<h2>SI1034CX-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI1034CX-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V SC89-6</p> <p>Datenblätter:  SI1034CX-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 104428 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1034CX-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 20V SC89-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	104428 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) 20V 610mA (Ta)
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	220mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	610mA (Ta)
Rds On (Max) @ Id, Vgs	396 mOhm @ 500mA, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	2nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	43pF @ 10V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1034CX-T1-GE3-ND

SI1034CX-T1-GE3 ist neu im Original, Suche SI1034CX-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1034CX-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1034CX-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1034X-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 0.18A SOT563F</p>	 <p>SI1034CX-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 20V SC89-6</p>	 <p>SI1034-A-GMR Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1034-B-GM3R Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>
 <p>SI1033X-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 0.145A SC89</p>	 <p>SI1034X-T1 VISHAY SI1034X-T1 VISHAY</p>	 <p>SI1034-B-GM3 Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1034-A-GM Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>

heiße Teile

Mehr

SI1029X-T1-GE3	SI1029X-T1-GE3	SI1031R-T1	SI1031R-T1-E3	SI1031R-T1-E3
SI1031R-T1-GE3	SI1031R-T1-GE3	SI1031X-T1	SI1031X-T1-E3	SI1031X-T1-E3
SI1031X-T1-GE3	SI1031X-T1-GE3	SI1032R-T1	SI1032R-T1-E3	SI1032R-T1-E3
SI1032R-T1-GE3	SI1032R-T1-GE3	SI1032X-T1	SI1032X-T1-E3	SI1032X-T1-E3
SI1032X-T1-GE3	SI1032X-T1-GE3	SI1033X-T1	SI1033X-T1-E3	SI1033X-T1-E3
SI1034CX-T1-GE3	SI1034X-T1	SI1034X-T1-E3	SI1034X-T1-E3	SI1034X-T1-GE3
SI1034X-T1-GE3	SI1035X-T1	SI1035X-T1-E3	SI1035X-T1-E3	SI1035X-T1-GE3
SI1035X-T1-GE3	SI1039X-T1-E3	SI1039X-T1-E3	SI1040X-T1-E3	SI1040X-T1-E3
SI1040X-T1-GE3	SI1040X-T1-GE3	SI1041ADY	SI1041DY-T1	SI1041DY-T1-E3
SI1045AB	SI1045ADY-T1	SI1046X-T1-E3	SI1046X-T1-GE3	SI1046X-T1-GE3

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